NSN 5962-01-464-7688

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set dcn e/i fscm 26512
Features Provided:
Monolithic and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leaded chip carrier
Product Name:
Microcircuit, memory, digital, cmos, field programmable gate array, 2000 gates, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Memory Device Type:
Pal
Special Features:
Bin speed - 142.9 ns
Test Data Document:
$96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
84 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0